Product data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

1.2 Features and benefits

- High voltage, current controlled RF resistor
- Low diode capacitance
- Low losses at very low currents
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

RF attenuators and switches

2. Pinning information

Table 1. Discrete pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|----------------------|--------|
| 1 | cathode | [1] | |
| 2 | anode | 1 2 | + |
| | | Transparent top view | sym006 |

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

| Type number | Package | | |
|-------------|------------|--|---------|
| | Name | Description | Version |
| BAP142LX | DFN1006D-2 | leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm | SOD882D |



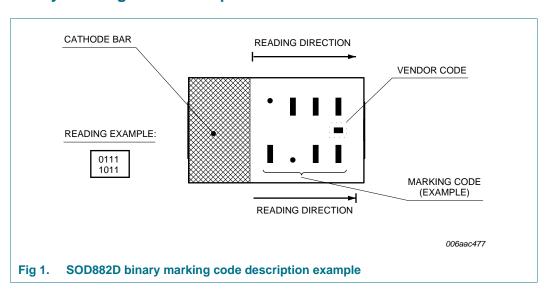
4. Marking

Table 3. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BAP142LX | 1001 |
| | 0010 |

^[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| | | 0 , , | , | | |
|------------------|-------------------------|-------------------------|-----|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V_R | reverse voltage | | - | 50 | V |
| I _F | forward current | | - | 100 | mA |
| P _{tot} | total power dissipation | T _{sp} = 90 °C | - | 130 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | -65 | +150 | °C |

6. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | 83 | K/W |

7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|--------------------------|--|-----|------|------|------|
| V_{F} | forward voltage | $I_F = 50 \text{ mA}$ | - | 0.95 | 1.1 | V |
| I _R | reverse current | V _R = 20 V | - | - | 20 | nA |
| | | V _R = 50 V | - | - | 100 | nA |
| C _d | diode capacitance | see Figure 2; f = 1 MHz; | | | | |
| | | $V_R = 0 V$ | - | 0.25 | - | pF |
| | | V _R = 1 V | - | 0.22 | - | pF |
| | | V _R = 20 V | - | 0.16 | 0.26 | pF |
| r_D | diode forward resistance | see Figure 3; f = 100 MHz; | | | | |
| | | I _F = 0.5 mA | - | 3.3 | 5.0 | Ω |
| | | I _F = 1 mA | - | 2.4 | 3.6 | Ω |
| | | I _F = 10 mA | - | 1.0 | 1.8 | Ω |
| | | I _F = 100 mA | - | 0.7 | 1.3 | Ω |
| ISL | isolation | see <u>Figure 4</u> ; V _R = 0 V; | | | | |
| | | f = 900 MHz | - | 18 | - | dB |
| | | f = 1800 MHz | - | 13 | - | dB |
| | | f = 2450 MHz | - | 11 | - | dB |
| L _{ins} | insertion loss | see Figure 5; I _F = 0.5 mA; | | | | |
| | | f = 900 MHz | - | 0.24 | - | dB |
| | | f = 1800 MHz | - | 0.24 | - | dB |
| | | f = 2450 MHz | - | 0.25 | - | dB |
| L _{ins} | insertion loss | see Figure 5; I _F = 1 mA; | | | | |
| | | f = 900 MHz | - | 0.18 | - | dB |
| | | f = 1800 MHz | - | 0.19 | - | dB |
| | | f = 2450 MHz | - | 0.25 | - | dB |
| L _{ins} | insertion loss | see Figure 5; I _F = 10 mA; | | | | |
| | | f = 900 MHz | - | 0.10 | - | dB |
| | | f = 1800 MHz | - | 0.11 | - | dB |
| | | f = 2450 MHz | - | 0.12 | - | dB |
| L _{ins} | insertion loss | see Figure 5; I _F = 100 mA; | | | | |
| | | f = 900 MHz | - | 0.07 | - | dB |
| | | f = 1800 MHz | - | 0.09 | - | dB |
| | | f = 2450 MHz | - | 0.10 | - | dB |
| τ_{L} | charge carrier life time | when switched from I $_{F}$ = 10 mA to I $_{R}$ = 6 mA; R $_{L}$ = 100 $\Omega;$ measured at I $_{R}$ = 3 mA | - | 0.11 | - | μS |
| L _S | series inductance | I _F = 100 mA; f = 100 MHz | - | 0.4 | - | nH |

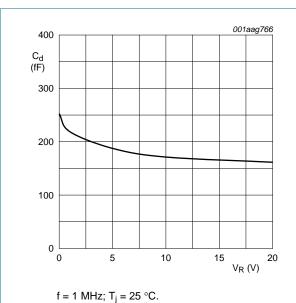
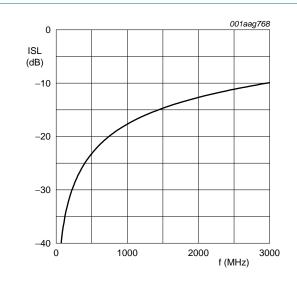


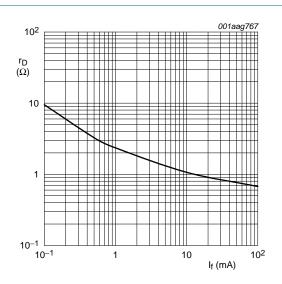
Fig 2. Diode capacitance as a function of reverse voltage; typical values



T_{amb} = 25 °C

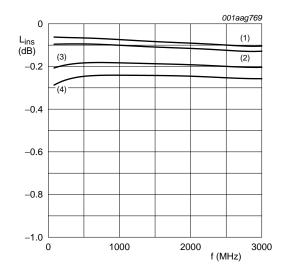
Diode zero biased and inserted in series with a 50 Ω stripline circuit





f = 100 MHz; $T_i = 25 \,^{\circ}\text{C}$.

Fig 3. Forward resistance as a function of forward current; typical values



T_{amb} = 25 °C

- (1) $I_F = 100 \text{ mA}$
- (2) $I_F = 10 \text{ mA}$
- (3) $I_F = 1 \text{ mA}$ (4) $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

Fig 5. Insertion loss of the diode as a function of frequency; typical values

8. Package outline

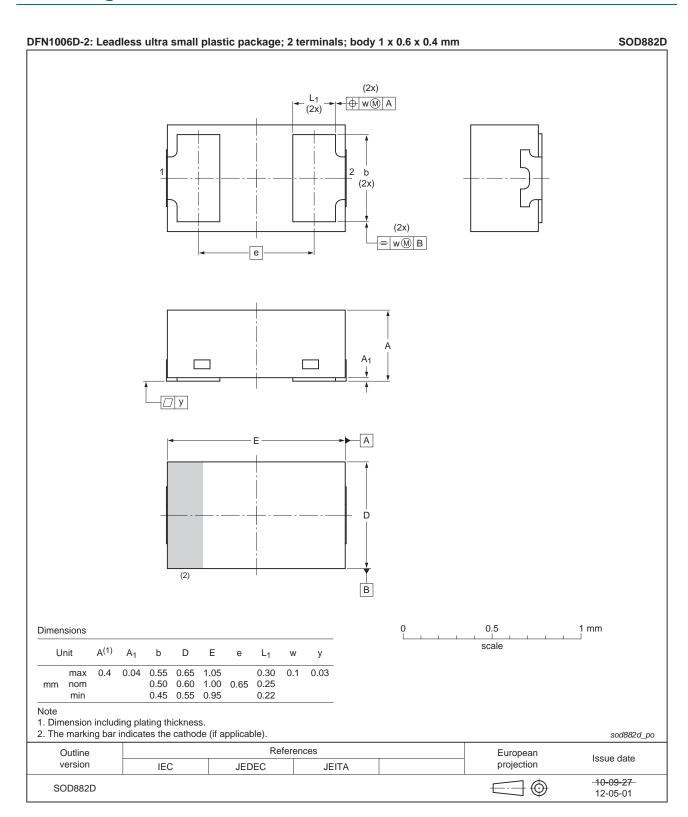


Fig 6. Package outline SOD882D (DFN1006D-2)

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9. Abbreviations

Table 7. Abbreviations

| Acronym | Description |
|---------|---------------------------|
| PIN | P-type, Intrinsic, N-type |
| SMD | Surface Mounted Device |
| RF | Radio Frequency |

10. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|---|----------------------------|---------------|--------------|--|--|
| BAP142LX v.2 | 20130806 | Product data sheet | - | BAP142LX v.1 | | |
| Modifications: | Section 1.1 on page 1: Changed package to SOD882D Table 1 on page 1: Changed simplified outline to SOD882D | | | | | |
| | Table 2 on page 1: Changed package to SOD882D | | | | | |
| | Section 4 o | n page 2: Update 'Marking' | section | | | |
| | Section 8 o | n page 5: Changed packag | e to SOD882D | | | |
| BAP142LX v.1 | 20070730 | Product data sheet | - | - | | |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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